GP1S36

Features

- Subminiature (4.0×4.2×3.8mm) (with built-in super compact ball for detecting tilt direction)
- 2. 2-phase output type
- 3. Able to detect the tilt direction of both side (±90°) by the position of rolling ball.
- 4. High reliability due to non-contact structure

Applications

- 1. Digital cameras
- 2. Camcoders

Abs	ngs	(Ta=25°C)			
	Parameter	Symbol	Rating	Unit	
	Forward current	IF	50	mA	
Input	Reverse voltage	VR	6	V	
	Power dissipation	Р	75	mW	
	Collector-emitter	VCE10	35	v	
	voltage	VCE20			
0	Emitter-collector	Ve1co	6	v	
Output	voltage	V _{E2} CO	6	v	
	Collector current	Ic	20	mA	
	Collector Power dissipation	Pc	75	mW	
	Total power dissipation	Ptot	100	mW	
Operating temperature		Topr	-25 to +85	°C	
Storage temperature		Tstg	-40 to +100	°C	
-	¹ Soldering temperature 1	Tsol	260	°C	
1	² Soldering temperature 2	Tsol	320	°C	

*1 For MAX. 5s

*2 For MAX. 2s at the position of 0.8mm from the bottomface of resin package by hand soldering.

Photointerrupter for Detecting Tilt Direction

Outline Dimensions

(Unit : mm)







 $(Ta=25^{\circ}C)$

Electro-optical Characteristics

	Paramete	er	Symbol	Conditions	MIN.	TYP.	MAX.	Unit	
Input	Forward voltage		VF	IF=20mA	_	1.2	1.4	V	
mput	Reverse curre	ent	Ir	V _R =3V	_	-	10	μΑ	
*3 Output	Collector dark	current	Iceo	Vce=20V	-	-	100	nA	
*3 Coupling Characteristics	Collector current		Ic	VCE=5V, IF=5mA	60	-	360	μA	
	*4 Leak current		ILEAK	VCE=5V, IF=5mA			15	μA	
	Response time	Rise time	tr	Vce=5V, Ic=100µA	_	50	150	μs	
		Fall time	tr	RL=1 000Ω	_	50	150	μs	
	Collector-emitter saturation voltage		VCE(sat)	IF=10mA, Ic=60µA	_	-	0.4	V	

*3 Output and coupling characteristics are common to the both phototransistors.

*4 Characteristics except leak current is measured at $\theta=0^{\circ}$, $\phi=0^{\circ}$.

Leak current is the output current of transistor when $\theta=\pm90^{\circ}$, $\phi=0^{\circ}$ and IC=OFF.

Detecting Angle Characteristics

θ	-90° ·	\leftrightarrow	–75°	\leftrightarrow	-15°	\leftrightarrow	+15°	\leftrightarrow	+75°	\leftrightarrow	+90°
Icı	ON						*5	*5 OFF			
Ic2		OFF	7	*5				ON			

Ic1 : Output current of phototransistors PT1

Ic2 : Output current of phototransistors PT2

 θ : Device condition : Refer to the figure

 ϕ : Device condition : Refer to the figure

ON :Output current of phototransistors : 60µA or more

OFF : Output current of phototransistors : 15µA or less

* Output current of ON/OFF is output when device is at a standstill

■ Supplement





Fig.1 Forward Current vs. Ambient Temperature



Fig.3 Forward Current vs. Forward Voltage



Fig.5 Collector Current vs. Collector-emitter Voltage



Fig.2 Power Dissipation vs. Ambient Temperature



Fig.4 Collector Current vs. Forward Current



Fig.6 Relative Collector Current vs. Ambient Temperature



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Fig.7 Collector-emitter Saturation Voltage vs. Ambient Temperature







Fig.8 Response Time vs. Load Resistance



Fig.10 Test Circuit for Response Time



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